

## Vishay Semiconductors

## **Small Signal Switching Diode**



#### **FEATURES**

- Silicon epitaxial planar diode
- AEC-Q101 qualified
- Material categorization:
  For definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>





ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

• Extreme fast switches

### **MECHANICAL DATA**

Case: DO-35

Weight: approx. 125 mg Cathode band color: black Packaging codes/options:

TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE						
PART	ORDERING CODE	ORDERING CODE TYPE MARKING INTERNAL CONSTRUCTION		REMARKS		
BAW75	BAW75-TAP	BAW75	Single diode	Ammopack		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Repetitive peak reverse voltage		V <sub>RRM</sub>	35	V		
Reverse voltage		$V_R$	25	V		
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	А		
Repetitive peak forward current		I <sub>FRM</sub>	450	mA		
Forward continuous current		I <sub>F</sub>	300	mA		
Average forward current	$V_R = 0$	I <sub>F(AV)</sub>	150	mA		
Dawer discination	I = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW		
Power dissipation	I = 4 mm, T <sub>L</sub> ≤ 25 °C	P <sub>tot</sub>	500	mW		

THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Thermal resistance junction to ambient air	I = 4 mm, T <sub>L</sub> = constant	R <sub>thJA</sub>	350	K/W		
Junction temperature		T <sub>j</sub>	175	°C		
Storage temperature range		T <sub>stq</sub>	- 65 to + 175	°C		

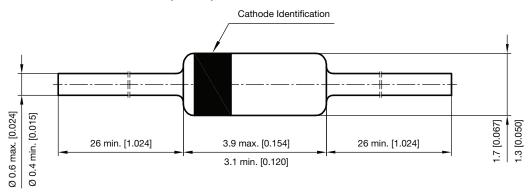


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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 30 mA	V <sub>F</sub>			1	V
Reverse current	V <sub>R</sub> = 25 V	I <sub>R</sub>			100	nA
neverse current	V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			100	μA
Breakdown voltage	$I_R = 5 \mu A, t_p/T = 0.01,$ $t_p = 0.3 \text{ ms}$	V <sub>(BR)</sub>	35			V
Diode capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz},$ $V_{HF} = 50 \text{ mV}$	C <sub>D</sub>			4	pF
	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$	t <sub>rr</sub>			4	ns
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 1 \text{ mA}, R_L = 100 \Omega$	t <sub>rr</sub>			2	ns

### PACKAGE DIMENSIONS in millimeters (inches): DO-35



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BAW75-TAP BAW75-TR